

Supplementary Information

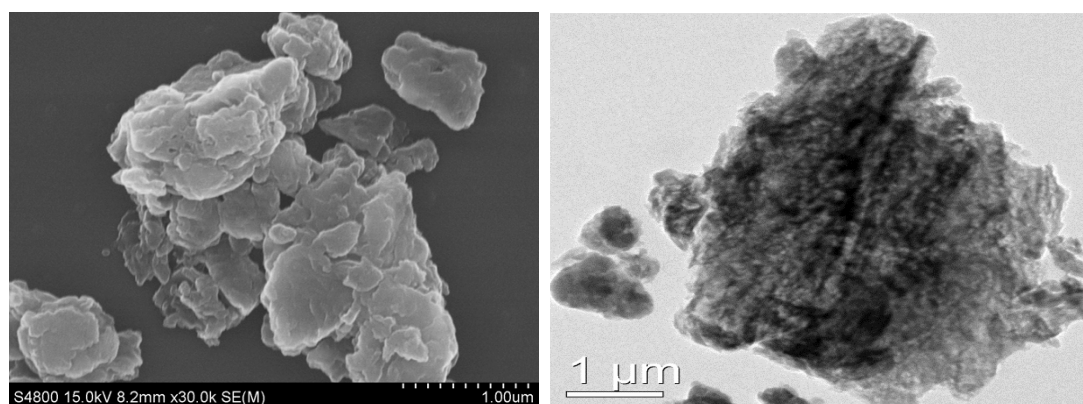


Fig. S1 TEM and SEM images of boron nitride at 900 °C for 3 h under NH_3 atmosphere.

Table S1 The effect of filler content on electrical resistivity of the PI nanocomposite films.

Sample	Content(wt%)	Volume resistance (Ω/cm^2)	Surface resistance ($\Omega\text{ cm}$)
Neat-PI	0	3.77×10^{14}	1.17×10^{13}
MWCNTs/PI	0.1	3.69×10^{14}	2.78×10^{12}
	1	1.66×10^{11}	1.48×10^{10}
	3	6.82×10^7	2.31×10^7
BN-c-MWCNTs/ PI	0.1	3.84×10^{14}	8.14×10^{12}
	1	4.51×10^{14}	4.49×10^{11}
	3	7.69×10^9	3.82×10^9

Table S2 Thermal conductivity of the MWCNTs/PI and BN-c-MWCNTs/PI nanocomposite films.

Sample	Content (wt%)	α (mm ² /s) ^a	ρ (g/cm ⁻³) ^b	c_p (J/gK) ^c	λ (W/mK) ^d
Neat-PI	0	0.141	1.268	1.049	0.188
MWCNTs/PI	0.1	0.204	1.311	1.146	0.306
	1	0.165	1.364	1.112	0.250
	3	0.175	1.373	0.993	0.239
BN-c-	0.1	0.211	1.301	1.146	0.315
MWCNTs/	1	0.204	1.467	1.067	0.319
PI	3	0.222	1.498	1.167	0.388

^a α : Thermal diffusivity, ^b ρ :Density, ^c c_p : Specific heat capacity, ^d λ :Thermal conductivity.